

# Standalone MC for LUXE GBP

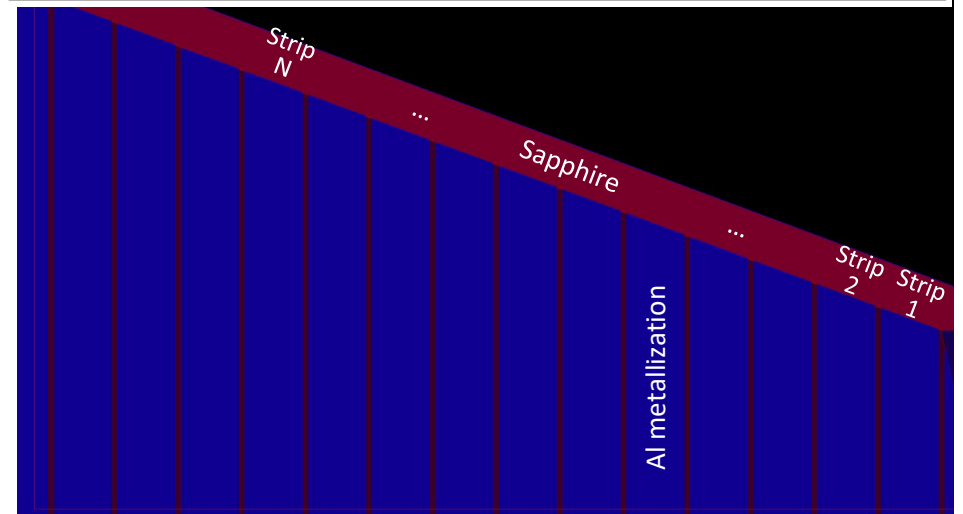
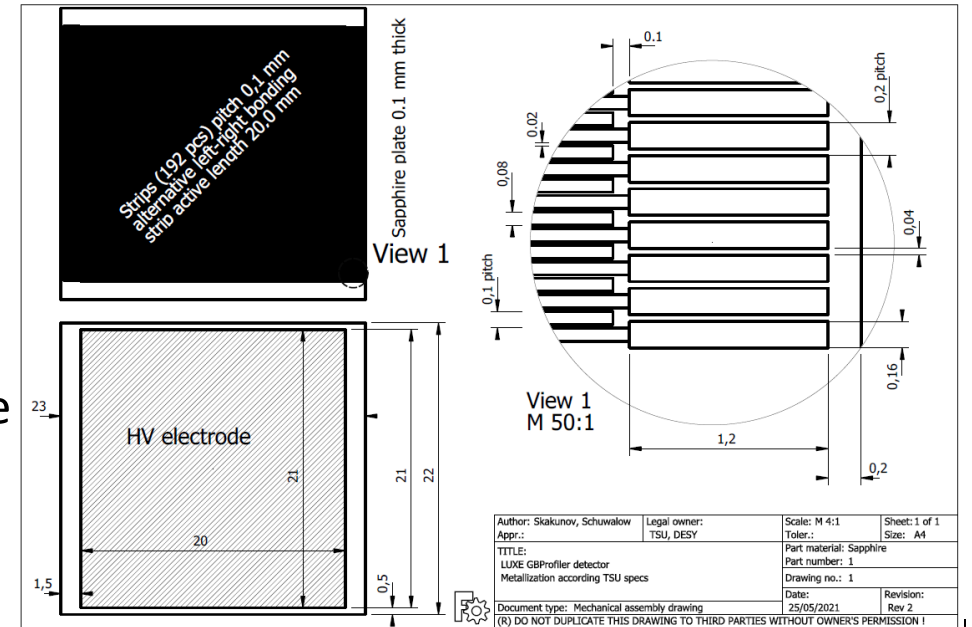
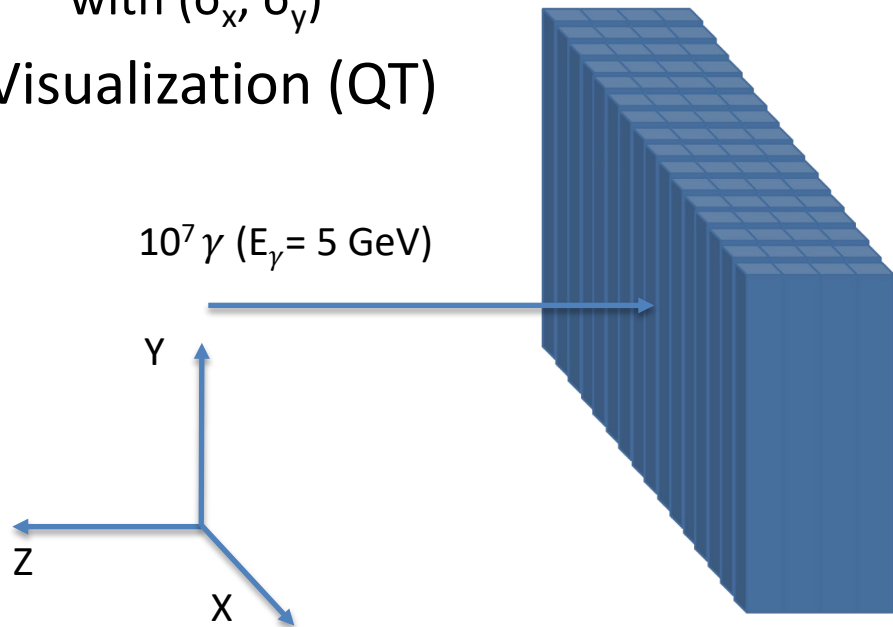
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## some updates



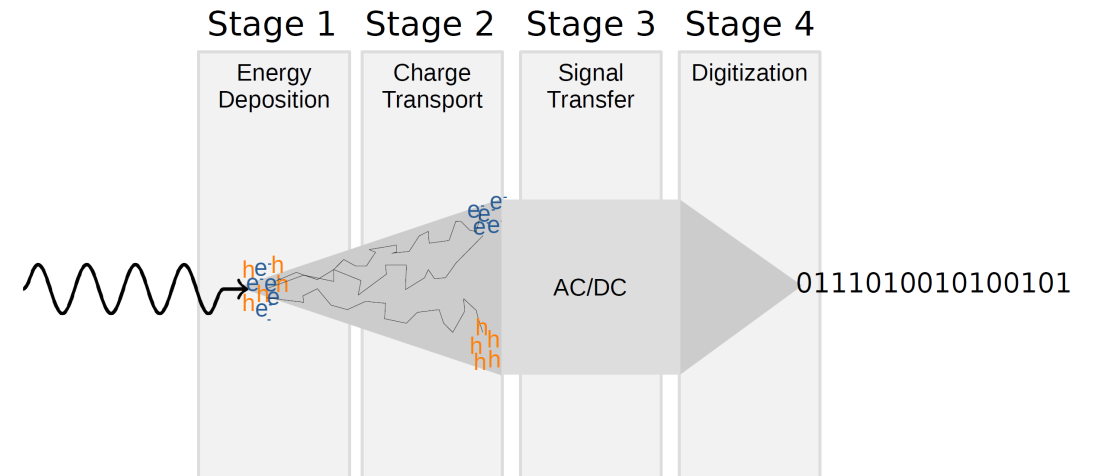
# Current status of the 'Standalone MC'

- Latest detector geometry was implemented
  - Front/rear metallization
  - Strip spacing
- Initial  $\gamma$  beam
  - It is directed along -z, gaussian distributed in the xy-plane with  $(\sigma_x, \sigma_y)$
- Visualization (QT)



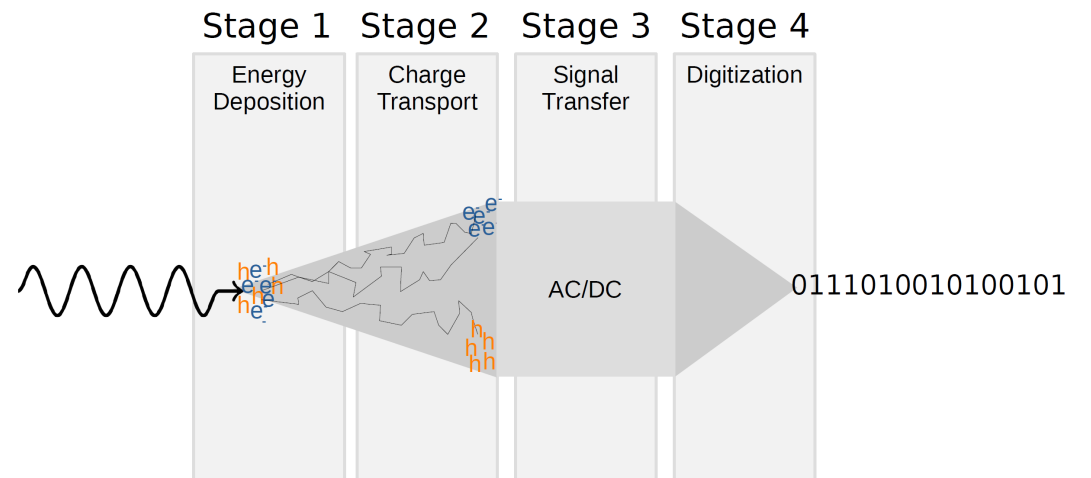
# What is next?

- The bare GEANT4 analysis allows to estimate the expected bare detector performance, for instance analysing energy deposits and charge particle production within the sensitive volumes.
- However, it is a priority to simulate the signal formation at the electrodes in order
  - to estimate the collection efficiency the detector;
  - to build a MC expectation for the experimental detector characterization data;
  - to optimize detector design.
- There are 3 steps leading to ‘The Waveform’
  - Energy deposition
  - Charge transport
  - Signal transfer



# Strategies and working plan

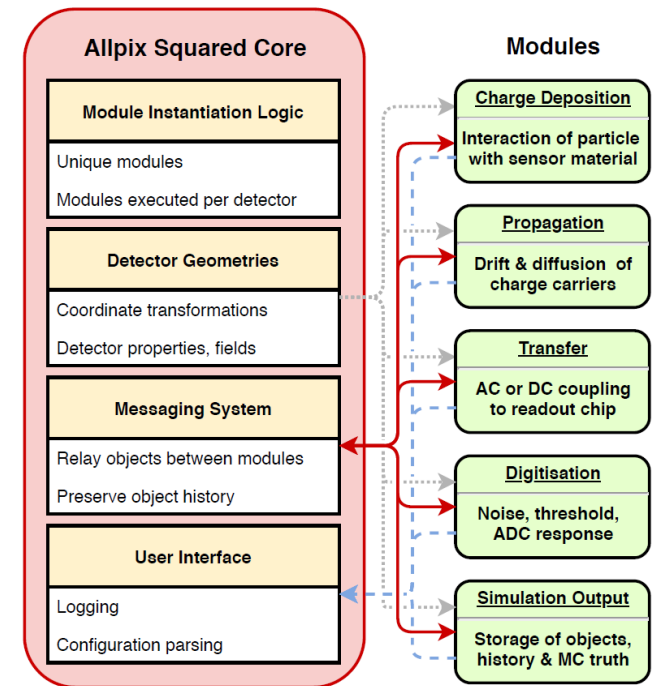
- There are several options to address this problem. They are divided in the two classes: the deterministic (or semideterministic) approach and the stochastic one.
- All the simulation frameworks considered are best suited for semiconductor detectors.
- Synopsys TCAD is considered the reference standard for silicon-based detector simulations. It solves the Poisson's equation using doping information, and it provides detailed information of the field configuration.
- On the other hand, Monte Carlo approaches
  - account stochastic effects;
  - can be inspected in every step;
  - the processes can be 'layered' in complexity;
  - the implementation of physical processes is clear and customizable in every line of code;
  - realistic performance with GEANT4 integration.



# Strategies and working plan

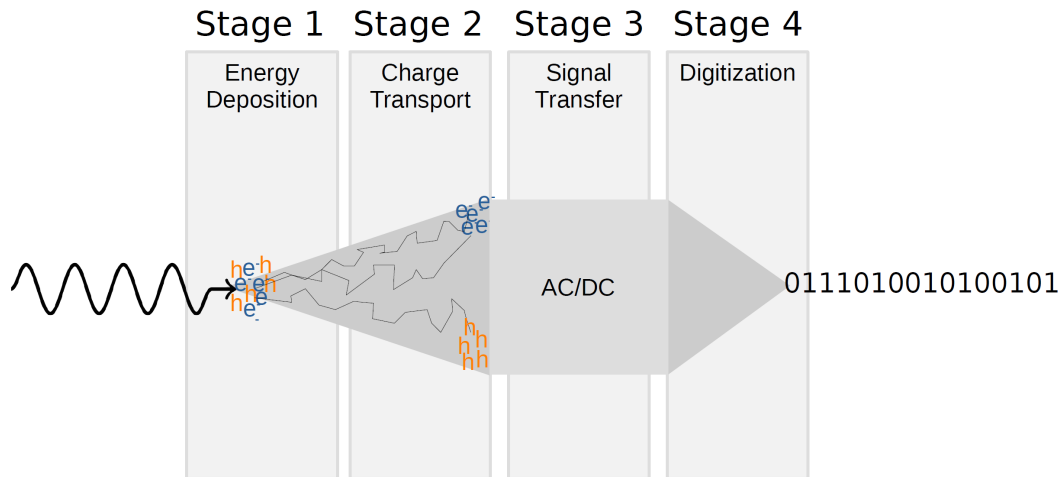
- The MC approach seems simpler, less time-demanding and easily integrable with other simulation frameworks (like GEANT4) by means of ROOT messengers.
- PixelAV, KdetSim, Garfield++, Weightfield2, AllPix1 are examples of packages for the charge transport / signal transfer.
- The candidate under consideration is AllPix<sup>2</sup> in combination with Weightfield2.

AllPix<sup>2</sup> is a generic, open-source software framework for the simulation of **silicon pixel** detectors. Its goal is to ease the implementation of detailed simulations for both single detectors and more complex setups such as beam telescopes *from incident radiation to the digitised detector response*.



# Why AllPix<sup>2</sup>?

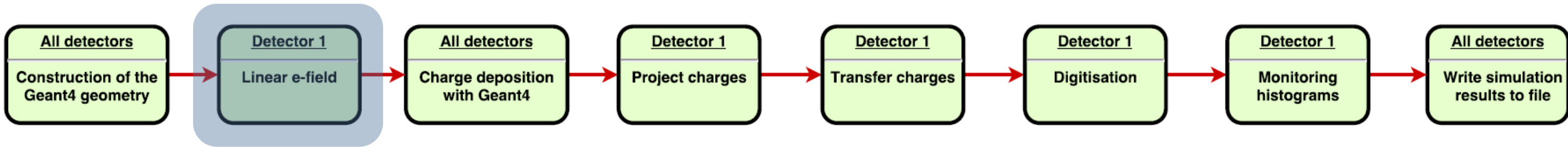
- Open code & multithread-ready
- Extremely easy GEANT and ROOT integrations
- Paul Schütze (DESY) is one of the authors
- Well documented manual (180 pp.)
- All the 4 steps are encompassed by a unique framework



- Many built-in physical processes for charge carrier mobility. Some models depend on the electric field strength to parametrize the mobility, others on the doping concentration of the device.
  - Jacoboni-Canali
  - Canali
  - Hamburg
  - Hamburg (2.5 keV/cm)
  - Masetti
  - Arora
  - Extended Canali
- Possibility to simulate finite charge carriers lifetimes as a function of local doping concentration via non-radiative recombination processes (Shockley-Read-Hall, Auger, both)

# What about Weightfield2?

- AllPix<sup>2</sup> default electric/magnetic field is zero. There are two presents for uniform fields.



- This approximation can be improved by a calculating the actual field configuration for a given geometry. This is the primary task of *Weightfield2*
  - Actual GEANT4 geometry is passed to Allpix2, and the weighfield2 code for evaluating the E field will be implemented as a module.

# Conclusions

- AllPix<sup>2</sup> seems the best candidate for the signal reconstruction.
  - Physical processes can be inferred precisely from the code
  - Ready-to-use GEANT4 geometries/data can be passed without any integrations
  - **ProjectionPropagation** module calculates the total drift time for each set of charge carriers by an analytical approx. of the mobility integral. Also, it applies a randomised lateral diffusion
  - **GenericPropagation** module allows for a more detailed transportation model by parametrisation of charge mobility.
  - **CapacitiveTransfer** module simulate crosscoupling between different pixels in order to emulate the behaviour of the assembly.